



LSF0102Q

AUTOMOTIVE 2-BITS BI-DIRECTIONAL LEVEL TRANSLATOR OPEN-DRAIN AND PUSH-PULL APPLICATIONS

Description

The LSF0102Q is an automotive compliant 2-channel bi-directional multi-voltage level translator for open-drain and push-pull applications. This device is a universal level translator that A port operates from 0.65V to 4.5V (Vref_A) and B port 1.8V to 5.5V (Vref_B). This range allows for bi-directional voltage translations between 0.65V and 5.0V. Be aware that Vref_B is recommended to be at 1.0V higher than Vref_A for best signal integrity.

The EN pin is used to activate the device. When EN is HIGH, the translator switch is on. Otherwise, EN is LOW, the translator switch is off, and a high-impedance state exists between ports. The EN input circuit is designed to be supplied by Vref_B via an external Rpu (pullup resistor, typ $200k\Omega$) and the EN must be LOW during power-up or power-down to avoid miss operation.

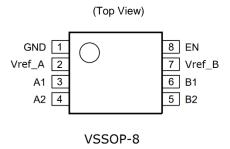
Be aware that external Rpu is required on each signal in both A and B ports for push-pull application because a pull-high state can avoid miss operation during power-up or power-down. As same as open-drain application, the smaller Rpu results in the larger driving current. For bidirectional signal flows, there is no need for a direction pin to minimize system effort. This device supports 5V tolerant I/O pins in a variety of applications which require different voltage translation levels.

Features

- AEC-Q100 Grade 1, Specified from -40°C to +125°C
- External Rpu (Pullup Resistor) Sets Driving Current in Both Push-Pull and Open-Drain Applications
- Maximum Data Rate is Dominated by the System Capacitance and Pullup Resistors
 - \leq 100MHz; C_L = 15pF, 30pF, R_{PU} <= 300Ω
 - \leq 50MHz; C_L = 50pF, R_{PU} <= 300 Ω
- Bi-directional Voltage Level Translation Between:
 - 0.65V and 1.5V, 1.8V, 2.5V, 3.3V and 5.0V
 - 1.2V and 1.8V, 2.5V, 3.3V and 5.0V
 - 1.8V and 2.5V, 3.3V and 5.0V
 - 2.5V and 3.3V and 5.0V
 - 3.3V and 5.0V
- ESD Protection Exceeds JESD 22
 - 4000V HBM (A114)
 - 1500V CDM (C101)
- Latch-Up Exceeds 100mA per JESD 17
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The LSF0102Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Pin Assignments



Applications

- GPIO, MDIO, SDIO, SVID, UART
- PMBus, SMBus, I2C, and other interfaces
- Infotainment head units
- ADAS computer visions
- Vehicle high-performance computing
- EV and HEV battery management systems

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Number	Pin Name	Function
1	GND	Ground
2	V _{ref_} A	Reference supply voltage; A port
3	A1	Input/output
4	A2	Input/output
5	B2	Input/output
6	B1	Input/output
7	V _{ref_B}	Reference supply voltage; B port
8	EN	Enable input (active HIGH)

Absolute Maximum Ratings (Note 4)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	±4	kV
ESD CDM	Charged Device Model ESD Protection	±1.5	kV
VREF	Supply Reference Voltage Range	-0.5 to +6.0	V
Vı	Input Voltage Range	-0.5 to +6.0	V
Vo	Voltage Range Applied to Any Output in the High-Z or Power-Off State	-0.5 to +6.0	V
I _{CH}	Continuous Channel Current	128	mA
lıĸ	Input Clamp Current, V _I < 0	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

4. Stresses greater than those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to Absolute Maximum Ratings for extended periods can affect device reliability.

Functional Diagram

NOTE: See load circuit.

EN pin is shorted to Vref_B with an external pull up resistor for gate bias voltage. Recommend: $200 \text{ k}\Omega$

Vref_A Vref_B
zeroΩ EN
to other channels



Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
Vref_A	Reference Voltage, A Port	0.65	4.5	V
\/maf D	Reference Voltage, B Port, when Vref_A >= 1V	Vref_A + 0.6	5.5	V
Vref_B	Reference Voltage, B Port, when Vref_A < 1V	Vref_A + 0.8	5.5	V
V _{I/O}	Input/Output Voltage	0	5.5	V
V	Enable Voltage when Vref_A >= 1V	Vref_A + 0.6	5.5	V
V _{EN}	Enable Voltage when Vref_A < 1V	Vref_A + 0.8	5.5	V
IPASS	Pass Transistor Current	_	64	mA
TA	Operating Free-Air Temperature	-40	+125	°C

Electrical Characteristics (All typical values are measured at T_A = +25 °C, unless otherwise specified.)

Symbol	Parameter		Test Conditions	Min	Тур	Max	Unit
Vref_A	A Port Supply Voltage	What if config to b	pe low-voltage side	0.65	_	4.5	V
Vref_B	B Port Supply Voltage	What if config to b	oe high-voltage side	1.8	_	5.5	V
V _{IK}	Input Clamping Voltage	I _I = -18mA, V _{EN} =	0	-1.2	_	_	V
ال	Leakage Current	Pins An, Bn, Vref_	A, Vref_B and EN; V _I = GND to 5.0V	_	1.0	5.0	μA
I _{cc}	Supply Current	Vref_B = EN = 5.5	$5V$, $Vref_A = 4.5V$, $I_O = 0$, $V_I = 0$ or V_{CC}	_	6	_	μA
C _{IO(off)}	I/O Pin Off-State Capacitance	Vo = 3V or 0, EN :	= 0	_	5	6	pF
C _{IO(on)}	I/O Pin On-State Capacitance	Vo = 3V or 0, EN :	= 3V	_	10	13	pF
C _{I(Vref_A/B/EN)}	Reference Voltage Pin and Enable Pin Input Capacitance	Vo = 3V or 0		_	10	_	pF
V _{IL} (EN)	Device Turn-Off Threshold of EN Pin	_	_			Vref_A	V
.,	Device Turn-On	When Vref_A >= 1	V. See load circuit.	Vref_A + 0.6	ı	5.5	V
V _{IH} (EN)	Threshold of EN Pin	When Vref_A < 1\	/. See load circuit.	Vref_A + 0.8	_	5.5	V
			Vref_A = 3.3V; Vref_B = EN = 5V	_	5	_	
		$V_1 = 0$, $I_0 = 64mA$	Vref_A = 1.8V; Vref_B = EN = 5V	_	6	_	Ω
			Vref_A = 1.0V; Vref_B = EN = 5V	_	9	_	
		V 0 1 00 A	Vref_A = 1.8V; Vref_B = EN = 5V	_	8	_	0
ь	On-State Resistance	$V_1 = 0$, $I_0 = 32mA$	V _I = 0, I _O = 32mA Vref_A = 2.5V; Vref_B = EN = 5V		6	_	Ω
R _{on}	(Note 5)	V _I = 1.8V, I _O = 15mA, Vref_A = 3.3V; Vref_B = EN = 5V		_	8	_	Ω
		V _I = 1.0V, I _O = 10mA, Vref_A = 1.8V; Vref_B = EN = 3.3V		_	14	_	Ω
		V _I = 0, I _O = 10mA, Vref_A = 1.0V; Vref_B = EN = 3.3V		_	10	_	Ω
		V _I = 0, I _O = 10mA	, Vref_A = 1.0V; Vref_B = EN = 1.8V	_	12	_	Ω
		V _I = 0, I _O = 10mA	, Vref_A = 0.65V; Vref_B = EN = 1.5V	_	15	_	Ω

Note: 5. Measured by the voltage drop between the A and B pins at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) pins.



Translating Down Switching Characteristics (TA = +25°C, unless otherwise specified.) (Note 6)

Translating Down, 5.0V to 1.8V

PARAMETER	FROM (INPUT)	TO (OUTPUT)	C∟ = 50pF	C _L = 30pF	C∟ = 15pF	UNIT	
TANAMETER	TROW (IN 01)	10 (0011 01)	Тур	Тур	Тур	ONT	
t _{PLH}	В	۸	0.4	0.3	0.2	ns	
t _{PHL}		A	1.0	0.7	0.5	ns	
Test Conditions: Vre	Test Conditions: Vref_A = 1.8V, V _{PU} = V _{IH} = 5.0V, V _M = 2.15V, PRR = 10MHz (unless otherwise noted, see load circuit)						

Translating Down, 3.3V to 1.8V

PARAMETER	FROM (INPUT)	TO (OUTPUT)	C _L = 50pF	C _L = 30pF	C _L = 15pF	UNIT
TANAMETER	TROW (IN 01)	10 (0011 01)	Тур	Тур	Тур	ONT
t _{PLH}	В	۸	0.4	0.3	0.2	ns
t _{PHL}		A	1.0	0.7	0.5	ns
Test Conditions: Vre	$f_A = 1.8V, V_{PU} = V_{IH}$	$I = 3.3V, V_M = 1.15V,$	PRR = 10MHz (unle	ss otherwise noted, s	ee load circuit)	

Translating Down, 3.3V to 1.2V

PARAMETER	EDOM (INDLIT)	FROM (INPUT) TO (OUTPUT)	C _L = 50pF	C _L = 30pF	C∟ = 15pF	UNIT		
I ANAMILIEN	T KOW (INI OT)	10 (0011 01)	Тур	Тур	Тур	ONIT		
t _{PLH}	Ь	۸	0.6	0.4	0.2	ns		
t _{PHL}	В	A	1.1	0.8	0.6	ns		
Test Conditions: Vre	Test Conditions: Vref_A = 1.2V, V _{PU} = V _{IH} = 3.3V, V _M = 0.85V, PRR = 10MHz (unless otherwise noted, see load circuit)							

Translating Down, 1.8V to 1.2V

PARAMETER FROM (INP	FROM (INPUT)	TO (OUTPUT)	C _L = 50pF	C _L = 30pF	C∟ = 15pF	UNIT	
I ANAMETER	T KOW (INI OT)	10 (0011 01)	Тур	Тур	Тур	Oldi	
t _{PLH}	В	۸	0.8	0.5	0.3	ns	
t _{PHL}		A	1.6	1.4	1.1	ns	
Test Conditions: Vre	Test Conditions: Vref_A = 1.2V, V _{PU} = V _{IH} = 1.8V, V _M = 0.65V, PRR = 10MHz (unless otherwise noted, see load circuit)						

Translating Down, 1.8V to 0.8V

PARAMETER	FROM (INPUT)	TO (OUTPUT)	C _L = 50pF	C _L = 30pF	C∟ = 15pF	UNIT		
TANAMETER	TROW (IN 01)	10 (0011 01)	Тур	Тур	Тур	OMI		
t _{PLH}	В	۸	0.8	0.5	0.3	ns		
t _{PHL}	Ь	A	1.6	1.2	1.0	ns		
Test Conditions: Vre	Test Conditions: Vref_A = 0.8V, V _{PU} = V _{IH} = 1.8V, V _M = 0.55V, PRR = 10MHz (unless otherwise noted, see load circuit)							

Translating Down, 1.5V to 0.65V

PARAMETER	FROM (INPUT)	TO (OUTPUT)	C _L = 50pF	C _L = 30pF	C∟ = 15pF	UNIT	
TANAMETER	TROW (IN 01)	10 (0011 01)	Тур	Тур	Тур	Oldin	
t _{PLH}	В	۸	1.0	0.6	0.4	ns	
t _{PHL}		A	1.9	1.5	1.1	ns	
Test Conditions: Vre	Test Conditions: Vref A = 0.65V, Vpu = ViH = 1.5V, VM = 0.4V, PRR = 10MHz (unless otherwise noted, see load circuit)						

Note: 6. All typical values are measured at $T_A = +25^{\circ}C$. Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 MHz$; $ZO = 50\Omega$. Definitions test circuit: $C_L = load$ capacitance including jig and probe capacitance; $R_L = load$ resistance = 300Ω ; $R_{PU} = ext$. pullup resistance = $200k\Omega$.



Translating Up Switching Characteristics (TA = +25°C, unless otherwise specified.) (Note 6)

Translating Up, 1.8V to 5.0V

PARAMETER	FROM (INPUT)	TO (OUTPUT)	C∟ = 50pF	C _L = 30pF	C∟ = 15pF	UNIT	
TANAMETER	TROW (IN 01)	10 (0011 01)	Тур	Тур	Тур	ONT	
t _{PLH}	Δ	В	0.4	0.3	0.3	ns	
t _{PHL}	^	В	1.9	1.4	1.0	ns	
Test Conditions: VIH	Test Conditions: V _{IH} = Vref_A = 1.8V, V _{EXT} = V _{PU} = 5.0V, R _L = 300Ω, V _M = 2.05V, PRR = 10MHz (unless otherwise noted, see load circuit)						

Translating Up, 1.8V to 3.3V

PARAMETER	FROM (INPLIT)	FROM (INPUT) TO (OUTPUT)	C _L = 50pF	C _L = 30pF	C∟ = 15pF	UNIT
TANAMETER	TROW (IN 01)	10 (0011 01)	Тур	Тур	Тур	ONT
t _{PLH}	۸	D	0.4	0.3	0.3	ns
t _{PHL}		В	1.9	1.4	1.0	ns
Test Conditions: VIH	= Vref_A = 1.8V, VEX	$T = V_{PU} = 3.3V, R_L =$	$300Ω$, $V_M = 0.9V$, PF	RR = 10MHz (unless	otherwise noted, see	load circuit)

Translating Up, 1.2V to 3.3V

PARAMETER	FROM (INPUT)	TO (OUTPUT)	C∟ = 50pF	C _L = 30pF	C∟ = 15pF	UNIT
TAXAMETER PROM (INFOT)		10 (0011 01)	Тур	Тур	Тур	Olan
t _{PLH}	Δ	В	0.4	0.3	0.2	ns
t _{PHL}	^		3.2	2.4	1.6	ns
Test Conditions: V _{IH} = Vref_A = 1.2V, V _{EXT} = V _{PU} = 3.3V, R _L = 300Ω, V _M = 0.75V, PRR = 10MHz (unless otherwise noted, see load circuit)						

Translating Up, 1.2V to 1.8V

PARAMETER	FROM (INPUT) TO	TO (OUTPUT)	C∟ = 50pF	C _L = 30pF	C∟ = 15pF	UNIT
			Тур	Тур	Тур	01411
t _{PLH}	۸	В	0.6	0.3	0.2	ns
t _{PHL}	A		2.8	2.2	1.6	ns
Test Conditions: VIH	= Vref_A = 1.2V, V _{EX}	$T = V_{PU} = 1.8V, R_L =$	$300Ω$, $V_M = 0.6V$, PF	RR = 10MHz (unless	otherwise noted, see	load circuit)

Translating Up, 0.8V to 1.8V

PARAMETER FROM	FROM (INPUT)	T) TO (OUTPUT)	C _L = 50pF	C _L = 30pF	C _L = 15pF	UNIT	
	TROM (INI 01)	10 (0011 01)	Тур	Тур	Тур	Oldi	
t _{PLH}	۸	В	0.6	0.3	0.2	ns	
t _{PHL}	A		3.7	2.9	2.1	ns	
Test Conditions: VIH	Test Conditions: V _{IH} = Vref_A = 0.8V, V _{EXT} = V _{PU} = 1.8V, R _L = 300Ω, V _M = 0.55V, PRR = 10MHz (unless otherwise noted, see load circuit)						

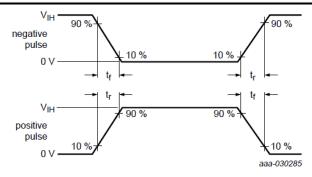
Translating Up, 0.65V to 1.5V

PARAMETER	FROM (INPUT)	TO (OUTPUT)	C _L = 50pF	C _L = 30pF	C _L = 15pF	UNIT
FARAMETER FROM (INFOT)		10 (0011 01)	Тур	Тур	Тур	ONII
t _{PLH}	۸	Р	0.7	0.3	0.2	ns
t _{PHL}	_ ^	Б	5.0	3.8	2.7	ns
Test Conditions: V _{IH} = Vref_A = 0.65V, V _{EXT} = V _{PU} = 1.8V, R _L = 300Ω, V _M = 0.4V, PRR = 10MHz (unless otherwise noted, see load circuit)						

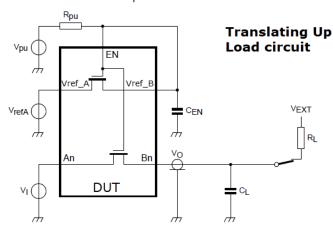
Note: 6. All typical values are measured at $T_A = +25^{\circ}C$. Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 MHz$; $ZO = 50 \Omega$. Definitions test circuit: $C_L = 10 MC$ capacitance including jig and probe capacitance; $R_L = 10 MC$ resistance R_L

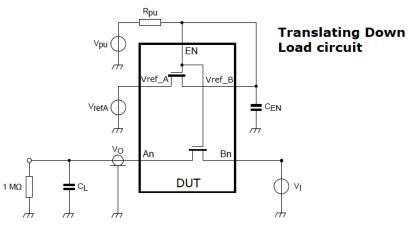


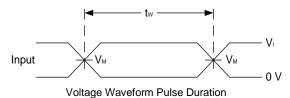
Parameter Measurement Information

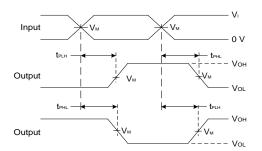


V_I source waveform









Voltage Waveform Propagation Delay Times Inverting and Non-Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms, R_{PU} = $200k\Omega$, C_{EN} = 0.1μ F, R_L = 300Ω , C_L = 15pF, 30pF, 50pF



Application Circuit Information

I2C or I3C protocol typically occurs in a modern application as shown in Figure 2. For the I2C or I3C voltage translation up or down, consideration should be taken for I3C because it is using higher speeds, which require careful design and attention to signal integrity to ensure reliable communication.

Since I3C uses open-drain mode when necessary for compatibility of I2C, but switches to push-pull outputs whenever possible. The existing I2C devices can be connected to an I3C bus but still have the bus able to switch to a higher data rate for communication at higher speeds between compliant I3C devices. Always refer to the I3C specifications and device datasheets for detailed information and recommendations to ensure reliable communication. Especially at higher speeds, which involve proper PCB layout, termination resistors, and cable selection based on your specific application requirements.

- Standard data rate (SDR): this is the default mode of I3C and operates at 11Mbps or 12.5Mbps.
- High data rate (HDR): this mode of I3C supports speeds up to 25Mbps where it is further enhanced to reach up to 33Mbps.
- Voltage levels: I3C supports a variety of voltage levels including 1.8V, 2.5V, 3.3V, and 5V.
- Output type: I3C utilizes both open-drain and push-pull outputs for SCL, offering flexibility for different voltage level combinations.
- Rise time and fall time: I3C defines minimum rise and fall times for the SCL signal to ensure proper signal integrity at different speeds.
- SCL is a conventional digital clock signal, driven with a push-pull output by the current bus controller during data transfers. When communication with known I3C targets occurs, the bus controller may switch to a higher frequency and/or alter the duty cycle.
- SDA carries the serial data stream, which may be driven by either a controller or target, but is driven at a rate determined by the controller's SCL signal. For compatibility with the I2C protocol, each transaction begins with SDA operating as an open-drain output, which limits the transmission speed. For messages addressed to an I3C target, the SDA driver mode switches to push-pull after the first few bits in the transaction, allowing the clock to be further increased.

Therefore, this presents a challenge with LSF0102Q for I3C because the LSF0102Q relies on a pullup resistor to translate the voltage up from the low-voltage side. The pullup resistor selected shall be not only strong enough to meet the timing requirements, but also not so strong that it violates the V_{IL} requirements of the I3C devices. So, the pullup resistors are needed on both sides for the normal translation setup. This means that the pullup resistors are required to pull the bus voltage on the high-voltage side from VPU_1 to VPU_2.

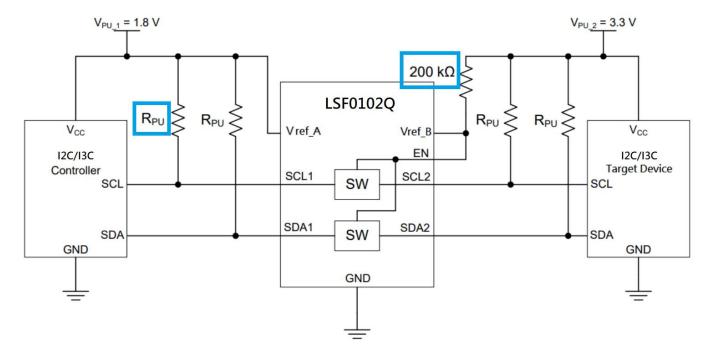


Figure 2. Typical Application Circuit for I2C or I3C Bus Voltage Translation



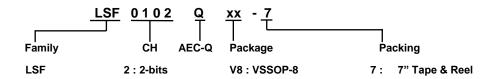
Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
θЈΑ	Thermal Resistance Junction-to-Ambient	VSSOP-8	(Note 7)	_	185	_	°C/W
θιс	Thermal Resistance Junction-to-Case	VSSOP-8	(Note 7)	_	54	_	C/VV

Note:

7. Test condition for each of the 3 package types: Device mounted on JEDEC standard PCB per JESD51, with minimum recommended pad layout.

Ordering Information

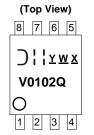


Orderable Bart Number	Part Number Suffix	Package Code	Poekage	Packing (Note 8)		
Orderable Part Number	Part Number Sumx		Package	Qty.	Carrier	
LSF0102QV8-7	-7	V8	VSSOP-8	3000	7" Tape and Reel	

Note: 8. The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information

VSSOP-8



 $\begin{array}{l} \underline{Y}: Year: 0 \text{ to } 9 \\ \underline{W}: Week: A \text{ to } Z: 1 \text{ to } 26 \text{ week}; \\ a \text{ to } z: 27 \text{ to } 52 \text{ week}; z \text{ represents} \end{array}$

52 and 53 week X: Internal Code

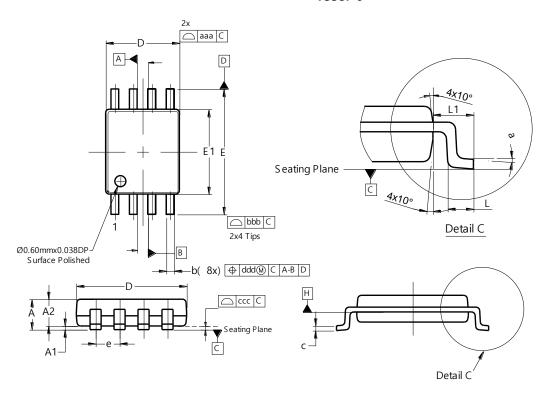
Orderable Part Number	Package	Identification Code
LSF0102QV8-7	VSSOP-8	V0102Q



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

VSSOP-8

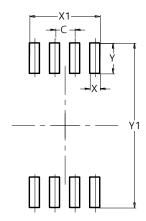


	VSSOP-8							
Dim	Min	Max	Тур					
Α	0.60	0.90						
A1		0.10						
A2	0.60	0.80						
b	0.17	0.25	0.21					
С	0.08	0.13						
D	1.90	2.10	2.00					
Е	3.20	3.60	3.40					
E1	2.20	2.40	2.30					
е		-	0.50					
L	0.30	0.40	0.35					
L1	0.50	0.60	0.55					
а	0°	6°	3°					
aaa	0.20							
bbb	0.25							
CCC	0.10							
ddd	0.13							
All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

VSSOP-8



Dimensions	Value (in mm)
С	0.500
Χ	0.250
X1	1.750
Y	0.750
V1	4.050

Mechanical Data

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.018 grams (Approximate)
- Max Soldering Temperature +260°C for 30 secs as per JEDEC J-STD-020



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